Quantum Electronics Laser Physics

Chapter 5.

The Laser Amplifier

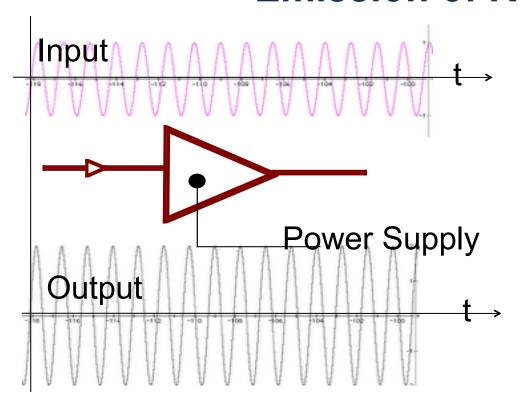
The laser amplifier

- 5.1 Amplifier Gain
- 5.2 Amplifier Bandwidth
- 5.3 Amplifier Phase-Shift
- 5.4 Amplifier Power source and rate equations
- 5.5 Amplifier non-linearity and gain saturation
- 5.6 Saturable absorbers

Laser: Light Amplification by Stimulated Emission of Radiation

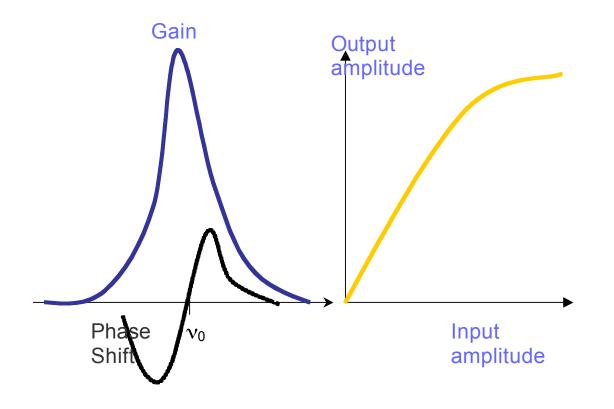
- Laser = coherent optical amplifier: increases the amplitude of an optical wave + maintains the phase
- Underlying physical process: stimulated emission of radiation (see Einstein theory in chapter 4)

Laser: Light Amplification by Stimulated Emission of Radiation



- Ideal amplifier:
 - Output scales linearly with input
 - Gain is constant in a certain bandwidth
 - Linear phase shift introduced by amplifier

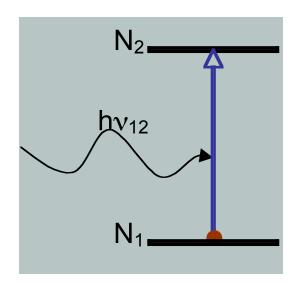
Laser: Light Amplification by Stimulated Emission of Radiation



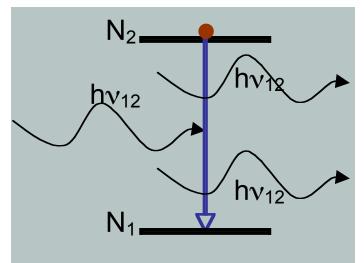
Real amplifier:

- Gain and phase shift (amplifier transfer function) are frequency dependent
- For large input values, the output saturates (nonlinear behaviour)

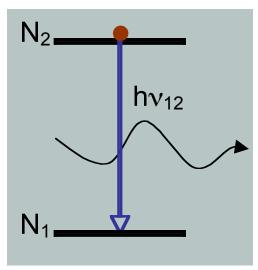
Elementary Interaction Processes



- Stimulated absorption: one photon lost
- Attenuation



- Stimulated emission: one photon gained
- Amplification
- Stimulated photon: same direction and phase



- Spontaneous emission: one photon emitted at random
- Noise

The Gain coefficient $\gamma(v)$

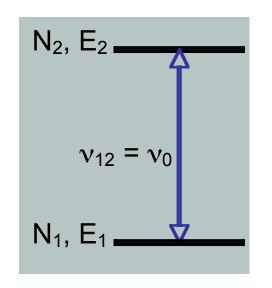
- Monochromatic plane wave travels in +z direction
- Through a medium of optical impedance η with resonance between levels
 1 and 2
- Intensity depends on z: I(z)
- Photon flux density Φ: number of photons per second per unit surface area of the medium

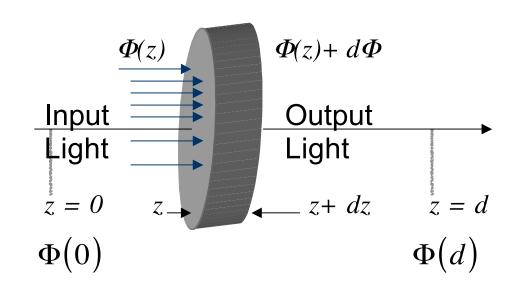
$$E(z) = Re \left[A_0 e^{i(2\pi vt - kz)} \right]$$

$$I(z) = \frac{|E(z)|^2}{2\eta}$$

$$\Phi(z) = \frac{I(z)}{h\nu}$$

The Gain coefficient $\gamma(v)$





- If the medium is amplifying:
 - Gain coefficient per unit length $\gamma(v)$
 - Phase shift per unit length $\varphi(v)$

The Gain coefficient $\gamma(\nu)$

W is the probability per unit time that a photon is absorbed or emitted by the stimulated processes:

$$d\Phi = (N_2 - N_1) \times W \times dz$$
$$d\Phi = N \times W \times dz$$

- If N > 0, there exists a population inversion and the medium is amplifying
- If N < 0, the medium attenuates and the photon flux decreases

The Gain coefficient $\gamma(v)$

W is given by Quantum Mechanics:

$$W = \Phi \times \sigma(v)$$

$$\sigma(v) \text{ is atomic cross-section}$$

$$d\Phi = N\Phi\sigma(v)dz = \gamma(v)\Phi dz$$

$$\gamma(v) = \text{ Gain coefficient} \quad \gamma(v) = N.\sigma(v)$$
After integration:
$$\Phi(z) = \Phi_0 e^{\gamma(v)z} \Rightarrow I(z) = I_0 e^{\gamma(v)z}$$
Overall for a length d of the amplifier:
$$\frac{\Phi(d)}{\Phi(0)} = G(v) = e^{\gamma(v)d}$$

$$\Phi(v) = \text{photon flux density} = \frac{I(v)}{hv}$$

The atomic cross-section $\sigma(v)$

• It is a fundamental atomic property characterising the "strength" of the emission or absorption processes in the E_2 - E_1 resonance.

$$\sigma_{ij}(v) = \frac{1}{4\pi\varepsilon_0} \frac{\pi e^2}{mc} \times f_{ij} \times g(v)$$

$$f_{ij} = \text{Oscillator strength of the i} \rightarrow j$$
value found in Tables of data (e.g NIST web site)
$$g(v) = \text{Normalized line shape function}$$

$$\int_{-\infty}^{+\infty} g(v) dv = 1$$

Atomic cross-section can be related to Einstein coefficients:

$$\sigma(v) = \frac{c^2}{8\pi v^2} A_{ij} g(v)$$

$$c^2 = 1$$

$$\sigma(v) = \frac{c^2}{8\pi v^2} \frac{1}{\tau_{ij}} g(v)$$

Amplifier bandwidth

- A band of frequencies will get amplified due to the lineshape function g(v).
- Lineshape is usually a Lorentzian curve L(v) (see chap.4). Thus, the gain curve $\gamma(v)$ is also a Lorentzian with same width.

$$\gamma(v) = N\sigma_{ij}(v) = N\frac{c^2}{8\pi v^2} \frac{1}{\tau_{ij}} g(v)$$

$$\gamma(v) = \gamma(v_0) \frac{(\Delta v/2)^2}{(v - v_0)^2 + (\Delta v/2)^2}$$

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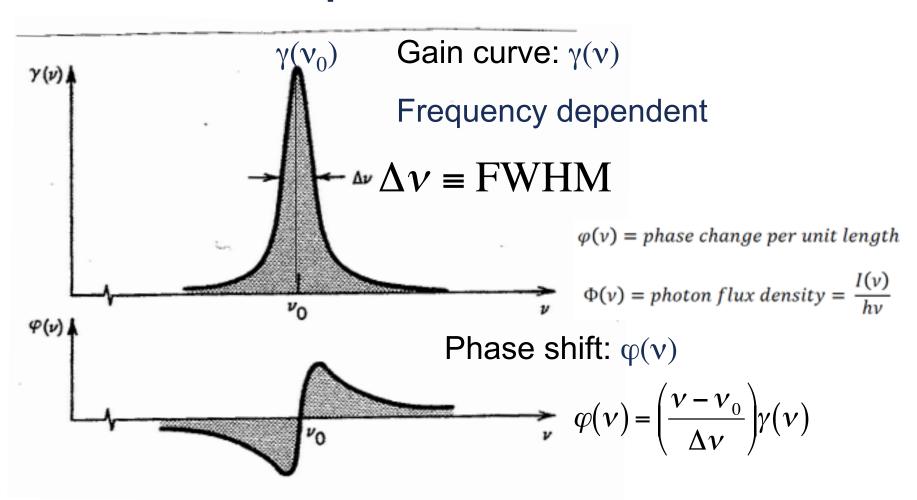
$$\gamma(v_0) = N\frac{c^2}{4\pi^2 v^2 \tau_{ij} \Delta v}$$

$$\gamma(v) = \gamma(v_0) \frac{(\Delta v/2)^2}{(v - v_0)^2 + (\Delta v/2)^2}$$

$$\gamma(v_0) = N \frac{c^2}{4\pi^2 v^2 \tau_{ij} \Delta v}$$

$$\equiv \text{ gain coefficient at centre of line}$$

Amplifier bandwidth



Amplifier Phase shift

At z, the optical field is

$$E(z) = E_0 e^{\int \frac{v(v)z}{2}} e^{-i\varphi(v)z} \varphi(v)$$
 = phase shift per unit length
Some Δz further, the field has increased by:

$$E(z + \Delta z) = E(z)e^{\int_{-2}^{2} \frac{\gamma(v)\Delta z}{2}} e^{-i\varphi(v)\Delta z} \approx E(z) \left[1 + \frac{\gamma(v)\Delta z}{2} - i\varphi(v)\Delta z\right]$$

(Using Taylor series expansion)

$$\Delta E(z) = E(z + \Delta z) - E(z)$$

$$\Rightarrow E(z) = E(z) \left[\frac{\gamma(v)\Delta z}{2} - i\varphi(v)\Delta z \right]$$

⇒ Output = Input Transfer function

Amplifier phase shift

 $-\varphi(v) = Hilbert Transform of \gamma(v)/2$

$$H'(v) = \frac{1}{\pi} \int_{-\infty}^{\infty} \frac{H''(s)}{s - v} ds$$

$$H''(\nu) = \frac{1}{\pi} \int_{-\infty}^{\infty} \frac{H'(s)}{\nu - s} ds$$

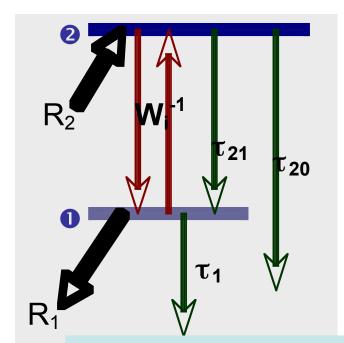
The amplifier phase shift is determined by its gain coefficient. If it is Lorentzian:

$$\varphi(v) = \left(\frac{v - v_0}{\Delta v}\right) \gamma(v)$$

 $\varphi(v)$ is zero at v_0 and small near v_0

- External power source is required to add to the input signal.
- To achieve amplification: pump must provide a population inversion on the transition of interest. Thermal equilibrium conditions do not exist: situation equivalent to "negative temperature" $N = (N_2 N_1) > 0$
- Pumping may be achieved
 - Optically (flashlamp, other laser)
 - Electrically (gas discharge, electron beam, injected charge carriers)
 - Chemically (excimer laser)
- For CW (continuous wave) operation, a steadystate population inversion must be maintained.

- Rate equations showing the balance between decay and excitation of the various levels involved must be considered:
 - Without amplifying radiation (green arrows)
 - With amplifying radiation (red



$$\frac{1}{\tau_2} = \frac{1}{\tau_{21}} + \frac{1}{\tau_{20}}$$

$$\frac{1}{\tau_2} = \text{Decay rate of 2}$$

$$\frac{1}{\tau_1} = \text{Decay rate of 1}$$

 R_1 = depopulating rate of level 1 due to pump (m⁻³s⁻¹).

 R_2 = populating rate of level 2 due to pump (m⁻³s⁻¹).

W_i -1 = time constant of stimulated processes

Rate
 equations in
 the absence
 of stimulated
 processes:

$$\frac{dN_2}{dt} = R_2 - \frac{N_2}{\tau_2}$$

$$\frac{dN_1}{dt} = -R_1 - \frac{N_1}{\tau_1} + \frac{N_2}{\tau_{21}}$$

Steady-state solution

$$\frac{dN_2}{dt} = \frac{dN_1}{dt} = 0$$

$$\Rightarrow (N_2 - N_1) = N = N_0$$

$$N_0 = R_2 \tau_2 \left(1 - \frac{\tau_1}{\tau_{21}} \right) + R_1 \tau_1$$

For large gains: large pump rates,

long
$$au_2$$
, short au_1

$$\frac{dN_1}{dt} = 0 => R_1 = \left(-\frac{N_1}{\tau_1} + \frac{N_2}{\tau_{21}}\right)$$

$$\frac{dN_2}{dt} = 0 => R_2 = \frac{N_2}{\tau_2}$$

$$N_2 = R_2 \tau_2$$

$$R_1 \tau_1 = -N_1 + \frac{N_2 \tau_1}{\tau_{21}}$$

$$N_1 = -R_1 \tau_1 + R_2 \frac{\tau_2 \tau_1}{\tau_{21}}$$

$$N_0 = N_2 - N_1 = R_2 \tau_2 + R_1 \tau_1 - R_2 \frac{\tau_2 \tau_1}{\tau_{21}}$$

$$N_0 = R_2 \tau_2 \left(1 - \frac{\tau_1}{\tau_{21}} \right) + R_1 \tau_1$$

- The upper level should be pumped strongly and decay slowly to retain its population.
- The lower level should decay/empty ("depump") fast.

Ideally:

$$\tau_{21} << \tau_{20} \Rightarrow \tau_2 \approx \tau_{21}$$
 (spontaneous rate) and $\tau_{21} >> \tau_1$

Simplified result obtains for N_0 :

$$N_0 \approx R_2 \tau_{21} + R_1 \tau_1$$

If further
$$R_1 = 0$$
 or $R_1 << \frac{\tau_{21}}{\tau_{21}} R_2$

$$\Rightarrow N_0 \approx R_2 \tau_{21} \text{ or } (R_2 \tau_{21}^{sp}) \text{ or } (R_2 t^{sp})$$

• N_0 controlled by: decay rates, pump rates and stimulated processes at rate W_i

$$\frac{dN_2}{dt} = R_2 - \frac{N_2}{\tau_2} - \frac{N_2W_i + N_1W_i}{\tau_2}$$

$$\frac{dN_1}{dt} = -R_1 - \frac{N_1}{\tau_1} + \frac{N_2}{\tau_{21}} + \frac{N_2W_i - N_1W_i}{\tau_{21}}$$

$$N = \frac{N_0}{1 + \tau_s W_i}$$

$$\frac{dN_2}{dt} = \frac{dN_1}{dt} = 0$$

Steady-state solution:

$$N = \frac{N_0}{1 + \tau_S W_i}$$

$$\tau_S = \tau_2 + \tau_1 \left(1 - \frac{\tau_2}{\tau_{21}} \right)$$

$$\equiv \text{ Saturation time constant } (\tau_S > 0)$$

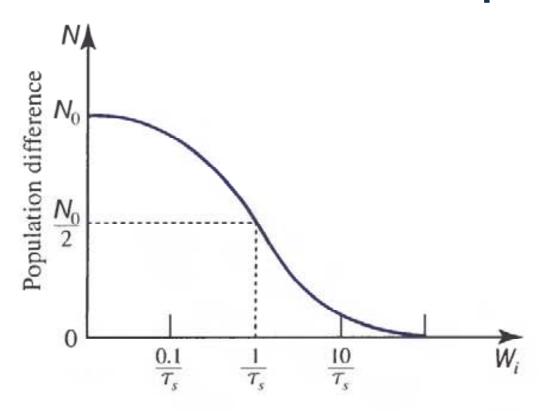
 $N = N_2 - N_1$ (in the presence of amplifier radiation) $N_0 = N_2 - N_1$ (in the absence of amplifier radiation)

 Steady-state population difference is smaller in presence of stimulated processes.

If $\tau_S W_i \ll 1 \Rightarrow N \approx N_0$ (small signal approximation).

 When large fluxes, stimulated processes dominate and population inversion becomes zero.

Recall $W_i = \phi \times \sigma(v) \Rightarrow \text{if } \tau_S W_i >> 1 \Rightarrow N \approx 0$ τ_S plays the role of saturation time constant.

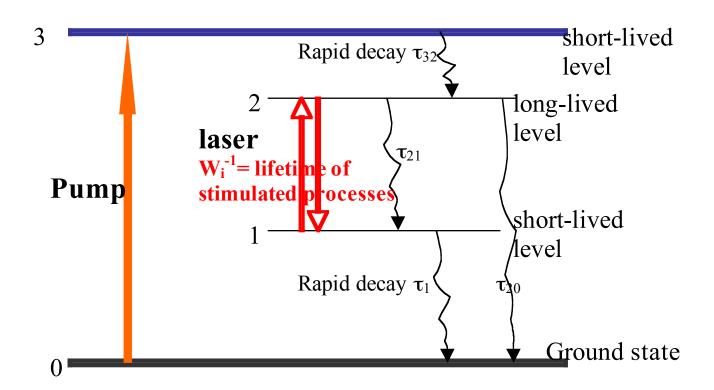


Adapted from Fundamental of Photonics, Saleh and Teich, 2nd ed. Wiley

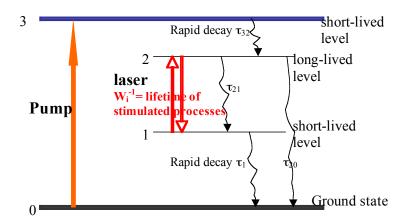
- Depletion of steady-state population difference as the rate of stimulated processes increases.
- Time constant = time to halve the initial inversion.

- Practical lasing schemes (population inversion between E_1 and E_2) involve 3 or 4 levels:
 - 4-level pumping schemes
 - 3-level pumping schemes
 - (Direct optical pumping of 2-level system does not achieve steady-state *N*).

Amplifier Power source: 4-level pumping scheme



- •In normal conditions, level 1 -the lower laser level- will be virtually unpopulated (highly desirable situation for the operation of the laser).
- There is little accumulation of population in level 3 as it decays non-radiatively to level 2 with a large transition probability.
- Level 2 is pumped via relaxation of level 3 and accumulates population.



- •R is the pumping rate: as decay of level 3 is very fast, pumping of level at a rate R is equivalent to pumping of level 2 at rate $R_2 = R$.
- •In this configuration, there is no pumping of atoms neither into nor out of level 1: $R_1 = 0$

In the absence of amplifier radiation ($W_i = \Phi = 0$), the steady-state population difference can be calculated:

$$N_0 = R\tau_2 \left(1 - \frac{\tau_1}{\tau_{21}} \right)$$

The non-radiative component of τ_{21} is negligible: $\tau_{21} \approx t_{sp}$

and
$$\tau_{20} >> t_{sp} >> \tau_1$$
.

$$N_0 = Rt_{sp}$$
 and $\tau_S \approx t_{sp}$

$$N \approx \frac{Rt_{sp}}{\left(1 + t_{sp}W_i\right)}$$

The pumping rate is however explicitely dependent on the population inversion :

$$N = N_2 - N_1$$
 (due to $N_g + N_1 + N_2 + N_3 = N_a$)

 N_a = Total atomic density = constant

Pumping at rate R depopulates N_g and populates N_3

with a transition probability W:
$$R = (N_g - N_3)W$$

Levels 1 and 3 are short-lived: $N_1 = N_3 = 0$

Then
$$N_g + N_2 = N_a \Rightarrow N_g \approx N_a - N_2 \approx N_a - N_a$$

The pumping rate $R \approx (N_a - N)W$

$$N \approx \frac{t_{sp} N_a W}{1 + t_{sp} W_i + t_{sp} W}$$

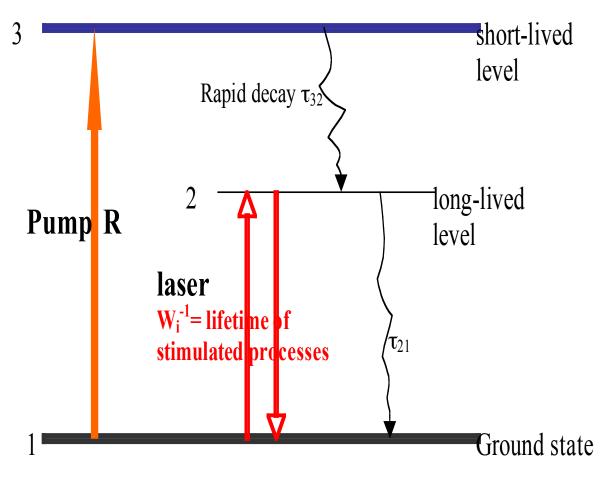
Rewritting in the form of $N = \frac{N_0}{1 + \tau_s W_i}$

$$N_0 \approx \frac{t_{sp} N_a W}{1 + t_{sp} W}$$
 and $\tau_S \approx \frac{t_{sp}}{1 + t_{sp} W}$

If weak pumping conditions $\left(W << \frac{1}{t_{s_p}}\right)$

$$N_0 = t_{sp} N_a W$$
 and $\tau_S \approx t_{sp}$

Retrieving the previous results



- Rapid 3-2 decay:no build up of population in 3
- •3-1 decay is slow: pumping populates upper laser level
- Population accumulates in 2 asGround state it's long-lived

Using the original set of rate equations:

$$\frac{dN_1}{dt} = \frac{dN_2}{dt} = 0 = R - \frac{N_2}{\tau_{21}} - N_2 W_i + N_1 W_i$$

 $N_1 + N_2 = N_a$ (as N_3 is negligible).

Solving for N_1 , N_2 , obtains the saturation time constant τ_s and the population inversion N_2 - N_1 .

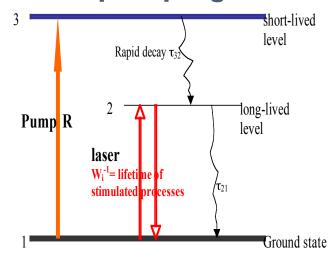
Using:
$$N = \frac{N_0}{1 + \tau_S W_i}$$

$$N_0 = 2R\tau_{21} - N_a$$

 $\tau_{\rm S} = 2\tau_{21} \approx 2t_{sp}$ (non-radiative processes are negligible).

To attain a population inversion $(N > 0 \text{ and } N_0 > 0)$ in 3-level system requires a pumping rate $R > N_a/2t_{sp}$. 3-level pumping scheme The corresponding pump power density is $E_3N_a/2t_{sp}$. $(E_3 : energy of level 3)$

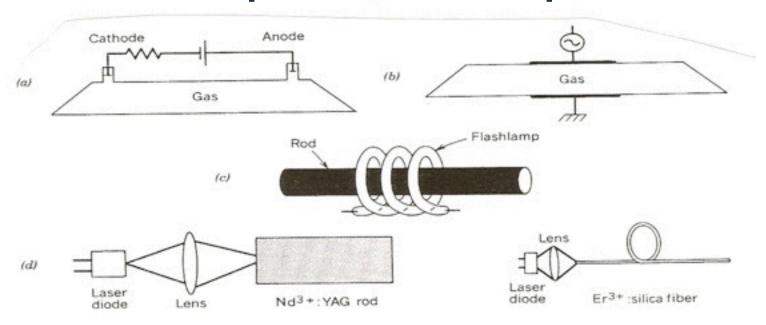
This is a large number as N_a is large (ground state). (compare with 4 - level system where the lower laser level 1 is normally empty).



$$R$$
 depends on N: $R = (N_1 - N_3)W$; $N_3 \approx 0$
 $N_1 + N_2 \approx N_a \Rightarrow N_1 = \frac{1}{2}(N_a - N)$,
thus: $R = \frac{1}{2}(N_a - N)W$

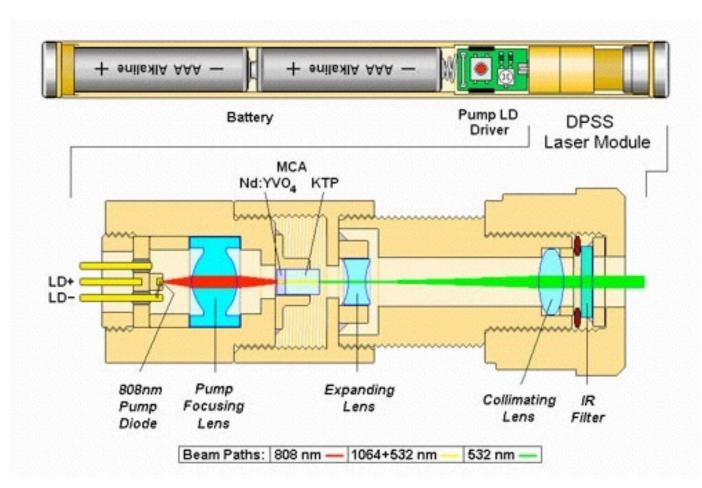
Substituting into:
$$N = \frac{2R\tau_{21} - N_a}{1 + 2t_{sp}W_i}$$
, rearranging
$$N_0 = \frac{N_a \left(t_{sp}W - 1\right)}{1 + t_m W} \text{ and } \tau_S \approx \frac{2t_p}{1 + t_m W}$$
 32

Examples of laser amplifier

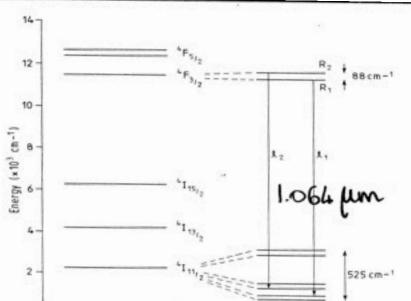


- a) and b) DC or RF discharge
- c) Flashlamp pump
- d) Laser pumps: laser diode pumps Nd:YAG rod or fiber laser

Diode pumped solid state frequencydoubled (DPSSFD) laser



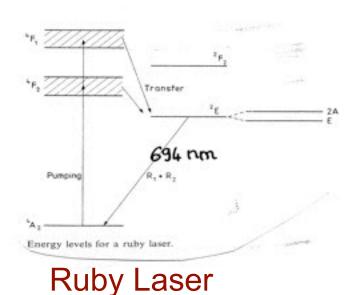
http://
en.wikipedia.
org/wiki/
Laser_pointe
r#Green



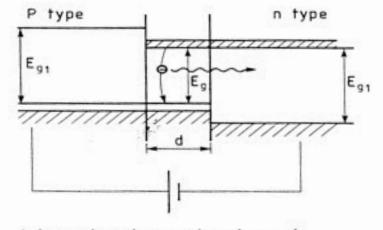
Nd:YAG Laser

Solid State laser amplifiers

The important energy levels for Nd:YAG crystal, showing the origin of the tw components, l_1 and l_2 , of the 1-064 μ m line.



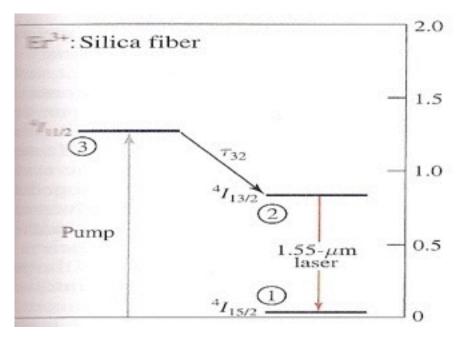
Laser Diode



A heterojunction semiconductor laser.

Erbium-doped silica fibre amplifier

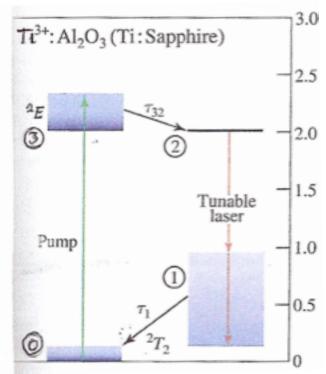


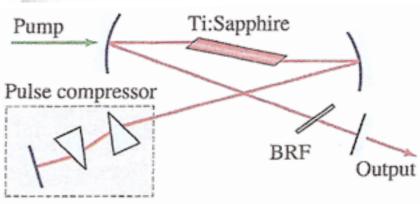


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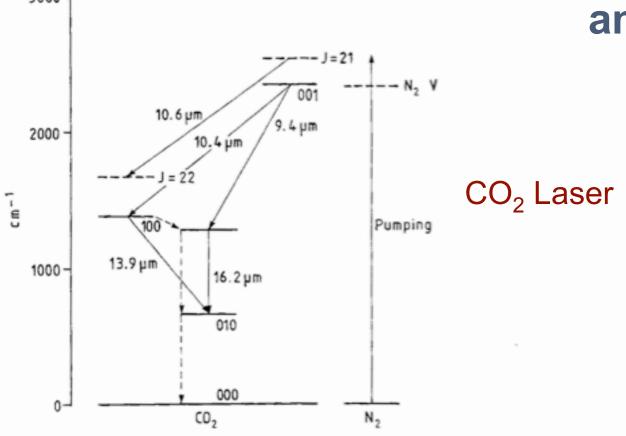
- Longitudinal pumping of EDFA (erbium-doped fibre amplifier) using 980 nm InGaAs QW laser diode
- 3-level pumping scheme at 300 K
- EDFA has high gain and high output power: 30 dB gain achieved with 5 mW of pump through 50 m of fibre (300 ppm Er₂O₃).
- High powers can be obtained (100W).

Titanium-sapphire laser

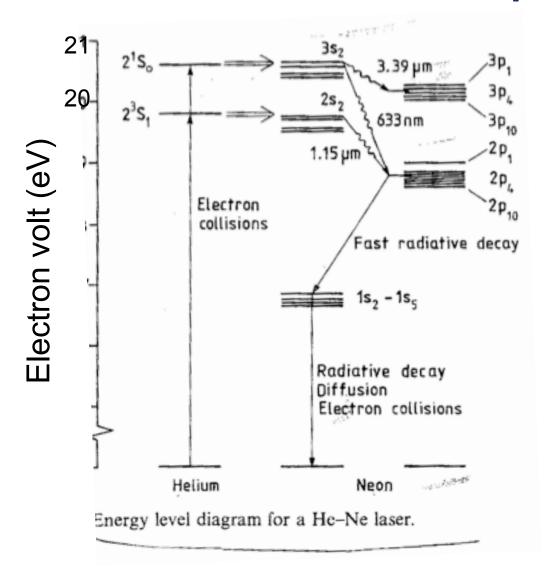




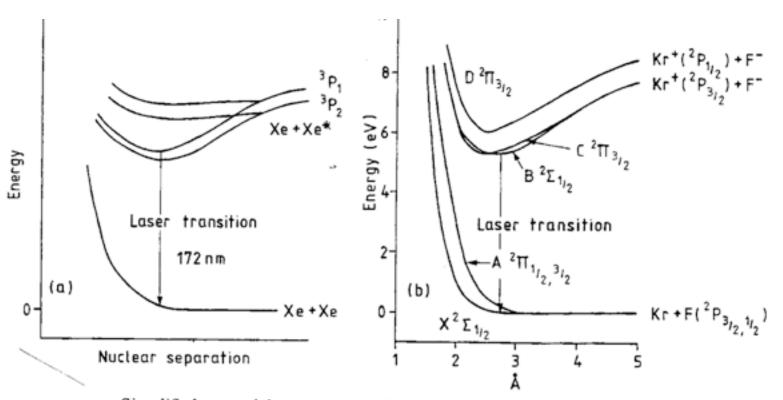
- Titanium Ti³⁺ ion dopants of sapphire matrix.
- Strong coupling of electronic levels to lattice vibrations: broadband vibronic levels (stimulated emission + phonons emission)
- Green pump is frequency-doubled Nd:YAG or green laser diode.
- 4-level pumping scheme
- Tunability is achieved by means of intracavity band pass filters (BRF: birefrengent rotatable filter at Brewster's angle): 700 nm - 1050 nm
- 5W when CW operation
- If mode-locked: 10 fs, 50 nJ, 80 MHz, 1 MW peak power



Lowest vibrational states in CO₂ showing the origin of the 9-4 μ m and 10-4 μ m bands. Strong relaxation paths are shown dotted. The position of the energy levels for the strongest transition in the 10-6 μ m P branch is also shown.



He-Ne (helium-neon)



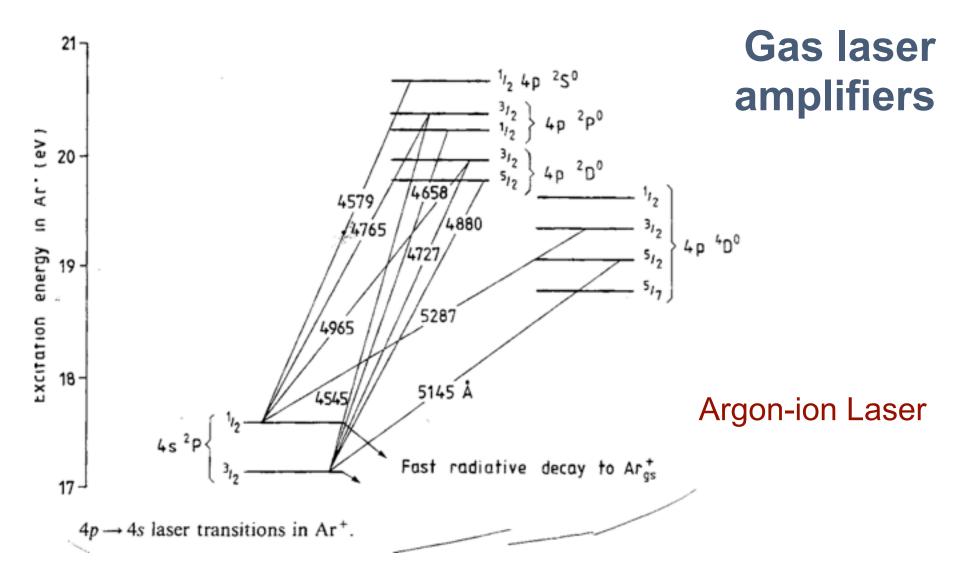
Simplified potential energy curve for (a) the lowest states of Xe₂ and (b) the lowest levels in KrF.

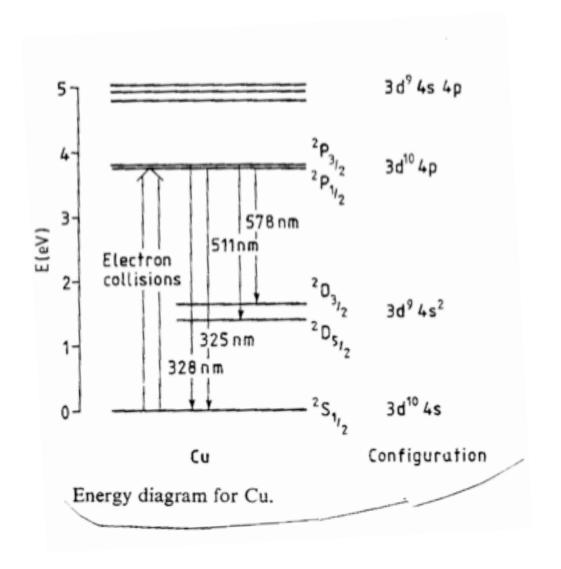
Excimer Laser

15 - $C^3\Pi_u$ Β ³Π₉ 10 -0.33 µm band Electron Energy (eV) collisions 0.75-0.97µm $X^{1}\Sigma_{u}^{+}$ 2.0 3.0 Nuclear separation (Å)

Gas laser amplifiers

Nitrogen Laser





Copper vapour Laser

 Nonlinearity and gain saturation arise due to dependence of the gain coefficient on photon flux.

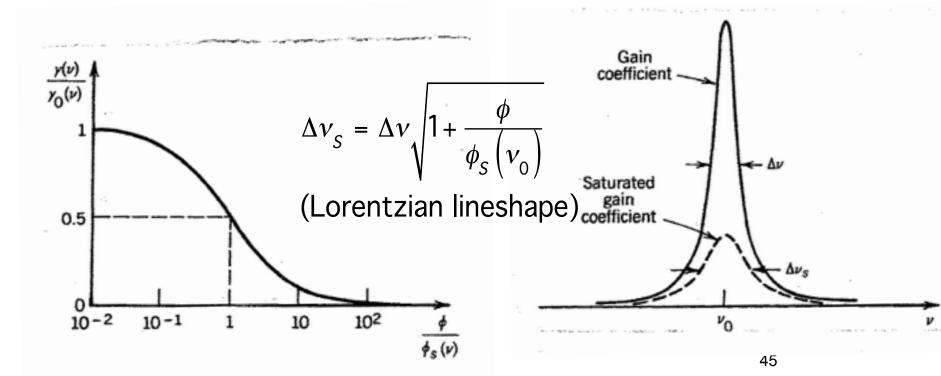
By definition:
$$W_i = \phi \sigma(v)$$
 and $N = \frac{N_0}{1 + \tau_S W_i}$

$$\Rightarrow N = \frac{N_0}{1 + \phi/\phi_S(v)} \text{ with } \frac{1}{\phi_S(v)} = \tau_S \sigma(v)$$

Since
$$\gamma(v) = N \times \sigma(v) \Rightarrow$$

$$\gamma(v) = \frac{\gamma_0(v)}{1 + \phi/\phi_S(v)} \text{ with } \gamma_0(v) = N_0 \times \sigma(v)$$

- Gain coefficient is a decreasing function of the photon flux density φ.
- Gain reduction is accompanied by increase in bandwidth:



- Behaviour of <u>saturated gain coefficient</u> in a homogeneously broadened laser amplifier of length d.
- Drop the frequency dependence out of notation for simplicity: $\gamma \equiv \gamma(v)$ and $\phi_S \equiv \phi_S(v)$

Basic gain:
$$d\phi = \gamma \phi dz$$
 (γ is now satured gain) \Rightarrow

$$\frac{d\phi}{dz} = \frac{\gamma_0 \phi}{1 + \phi/\phi_S} \Rightarrow \int_0^z \gamma_0 dz = \int_0^z \frac{1}{\phi} (1 + \phi/\phi_S) d\phi$$

$$\gamma_0 z = \left[\phi/\phi_S + Ln\phi \right]_0^z$$

$$Ln \frac{\phi(z)}{\phi_0} + \frac{\phi(z) - \phi_0}{\phi_0} = \gamma_0 z$$

$$\phi_0 \text{ Should be Phi(s) and not Phi (0)..}$$

Solving for $\phi(z)$ and using the variables:

Normalised input photon-flux density:
$$X = \frac{\phi(0)}{\phi_S}$$

Normalised output photon-flux density: $Y = \frac{\phi(d)}{\phi_S}$

Overall gain:
$$G = \frac{Y}{X} = \frac{\phi(d)}{\phi(0)}$$

$$[LnY + Y] = [LnX + X] + \gamma_0 d$$

Two limiting cases:

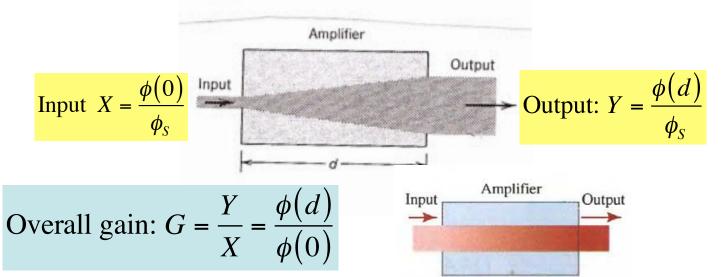
- (1) X and Y << 1: Photon flux densities small (below saturation)
- (2) $X \gg 1$ (Large initial photon flux)

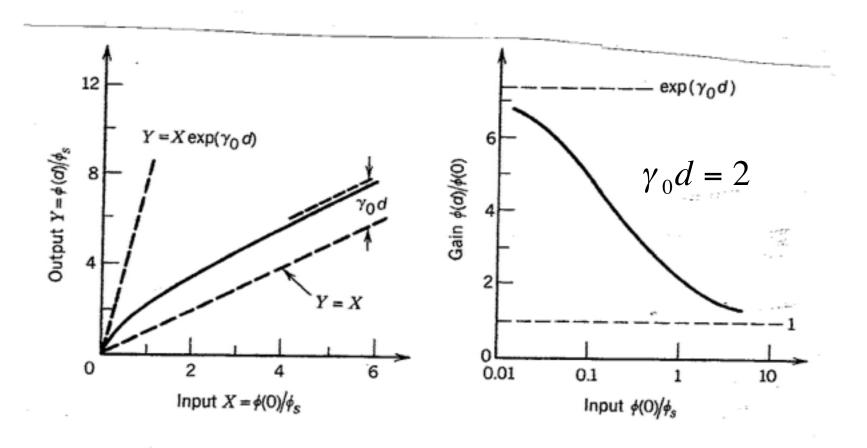
(1)
$$LnY \approx LnX + \gamma_0 d \Rightarrow G = e^{\gamma_0 d}$$

Small signal case: gain is independent of photon flux

(2)
$$Y \approx X + \gamma_0 d \Rightarrow \phi(d) \approx \phi(0) + \gamma_0 \phi_S d \approx \phi(0) + \frac{N_0 d}{\tau_S}$$

Heavily saturated conditions: initial flux augmented by constant flux $\gamma_0 \phi_s d$ independent of amplifier input.



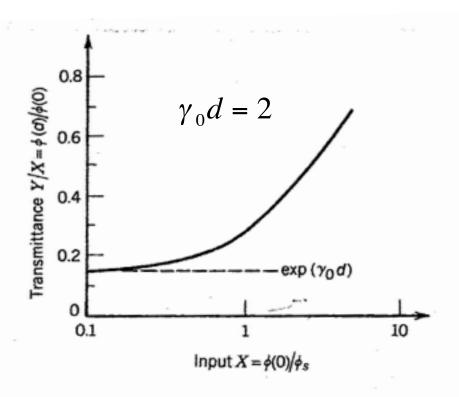


Saturable absorbers

- If the gain coefficient is <0, the medium attenuates, there is no population inversion $(N_0 < 0)$.
- The attenuation (absorption) coefficient is: $\alpha(v) = -\gamma(v)$
- It also suffers from saturation:

$$\alpha(v) = \frac{\alpha_0(v)}{1 + \phi/\phi_S(v)}$$

Saturable absorbers



Saturable absorbers are widely used to pulse lasers (passive Q-switching or mode-locking).

• Same flux equation with $\gamma_0 < 0$

$$[LnY + Y] = [LnX + X] + \gamma_0 d$$

- Transmittance increases for increasing input photon-flux density.
- The medium transmits more due to the effect of stimulated emissions